

# US2A THRU US2M SURFACE MOUNT ULTRA FAST SWITCHING RECTIFIER VOLTAGE: 50 TO 1000V CURRENT: 2.0A

ΤM

TECHNICAL SPECIFICATION

#### FEATURES

- Ideal for surface mount pick and place application
- Low profile package
- Built-in strain relief
- High surge capability
- Glass passivated chip
- Ultra fast recovery for high efficiency
- High temperature soldering guaranteed: 260°C/10sec/at terminal

## **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O
  - recognized flame retardant epoxy
- Polarity: Color band denotes cathode

#### SMA/DO-214AC В С - D G ⊣н MAX. .110(2.79) .177(4.50) .058(1.47) .012(0.305) MIN. .100(2.54) .157(3.99) <u>.052(1.32)</u>.006(0.152) MAX. .208(5.28) .090(2.29) .008(0.203) .060(1.52) MIN. | .194(4.93) | .078(1.98) |.004(0.102) | .030(0 **Dimensions in inches and (millimeters)**

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	US2 A	US2 B	US2 D	US2 G	US2 J	US2 K	US2 M	UNITS
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current $(T_L=90^{\circ}C)$	I <sub>F(AV)</sub>	2.0						А	
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	50						А	
Maximum Instantaneous Forward Voltage (at rated forward current)	$V_{F}$	1.0 1.4 1				1.7		V	
Maximum DC Reverse Current $T_a=25^{\circ}C_a$ (at rated DC blocking voltage) $T_a=100^{\circ}C_a$		5.0 350					μΑ μΑ		
Maximum Reverse Recovery Time (Note 1	) trr	50 75					nS		
Typical Junction Capacitance (Note 2	) C <sub>J</sub>	25						pF	
Typical Thermal Resistance (Note 3	) R <sub>θ</sub> (ja)	20						°C/W	
Storage and Operation Junction Temperature Note:	$T_{STG},T_{J}$	-50 to +150						°C	

1. Reverse recovery condition  $I_F=0.5A$ ,  $I_R=1.0A$ , Irr=0.25A.

2.Measured at 1.0 MHz and applied voltage of  $4.0 V_{dc}$ 

3. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area